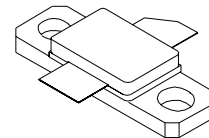


**SD57045****RF POWER TRANSISTORS***The LdmoST FAMILY***N-CHANNEL ENHANCEMENT-MODE LATERAL MOSFETs**

- EXCELLENT THERMAL STABILITY
- COMMON SOURCE CONFIGURATION
- $P_{OUT} = 45W$ WITH 13 dB gain @ 945 MHz
- BeO FREE PACKAGE

DESCRIPTION

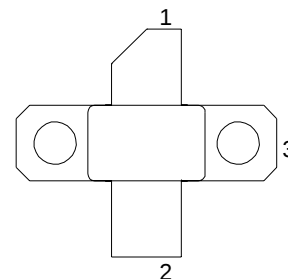
The SD57045 is a common source N-Channel enhancement-mode lateral Field-Effect RF power transistor designed for broadband commercial and industrial applications at frequencies up to 1.0 GHz. The SD57045 is designed for high gain and broadband performance operating in common source mode at 28 V. It is ideal for base station applications requiring high linearity.



M243
epoxy sealed

ORDER CODE
SD57045

BRANDING
SD57045

PIN CONNECTION

1. Drain
2. Gate

3. Source

ABSOLUTE MAXIMUM RATINGS ($T_{CASE} = 25^{\circ}C$)

Symbol	Parameter	Value	Unit
$V_{(BR)DSS}$	Drain-Source Voltage	65	V
V_{DGR}	Drain-Gate Voltage ($R_{GS} = 1 M\Omega$)	65	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current	5	A
P_{DISS}	Power Dissipation (@ $T_c = 70^{\circ}C$)	93	W
T_J	Max. Operating Junction Temperature	200	$^{\circ}C$
T_{STG}	Storage Temperature	-65 to + 200	$^{\circ}C$

THERMAL DATA

$R_{th(j-c)}$	Junction -Case Thermal Resistance	1.4	$^{\circ}C/W$
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ELECTRICAL SPECIFICATION ($T_{CASE} = 25^{\circ}C$)

STATIC

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
$V_{(BR)DSS}$	$V_{GS} = 0\text{ V}$	$I_{DS} = 1\text{ mA}$	65			V
I_{DSS}	$V_{GS} = 0\text{ V}$	$V_{DS} = 28\text{ V}$			1	μA
I_{GSS}	$V_{GS} = 20\text{ V}$	$V_{DS} = 0\text{ V}$			1	μA
$V_{GS(Q)}$	$V_{DS} = 28\text{ V}$	$I_D = 250\text{ mA}$	2.5		5.0	V
$V_{DS(ON)}$	$V_{GS} = 10\text{ V}$	$I_D = 3\text{ A}$		0.7	0.9	V
G_{FS}	$V_{DS} = 10\text{ V}$	$I_D = 5\text{ A}$	2.0	2.7		mho
C_{ISS}	$V_{GS} = 0\text{ V}$	$V_{DS} = 28\text{ V}$		80		pF
C_{OSS}	$V_{GS} = 0\text{ V}$	$V_{DS} = 28\text{ V}$		40		pF
C_{RSS}	$V_{GS} = 0\text{ V}$	$V_{DS} = 28\text{ V}$		3.2		pF

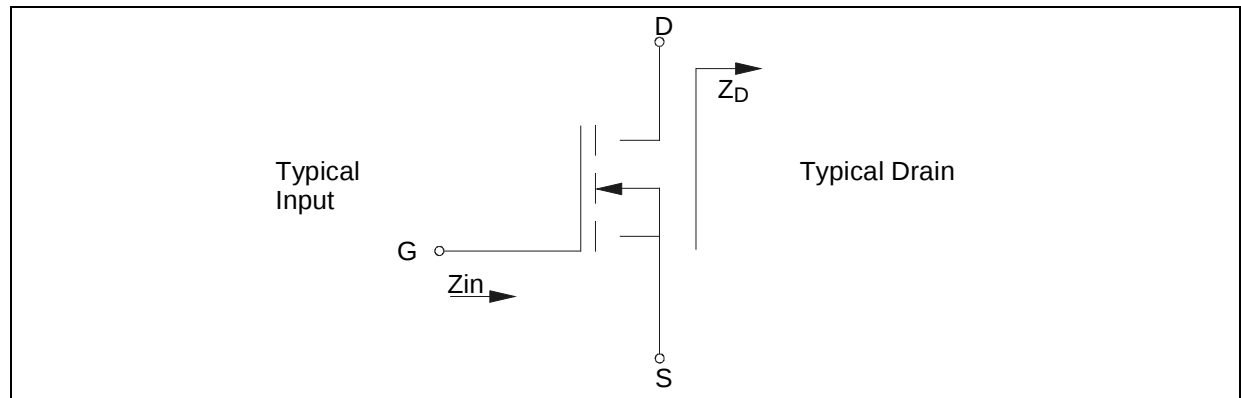
Ref. 7133620B

DYNAMIC

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
P_{OUT}	$V_{DD} = 28\text{ V}$	$I_{DQ} = 250\text{ mA}$ $f = 945\text{ MHz}$	45			W
IMD3	$V_{DD} = 28\text{ V}$	$I_{DQ} = 250\text{ mA}$ $P_{OUT} = 45\text{ W PEP}$		-32	-28	dBc
G_{PS}	$V_{DD} = 28\text{ V}$	$I_{DQ} = 250\text{ mA}$ $P_{OUT} = 45\text{ W PEP}$	13	15		dB
η_D	$V_{DD} = 28\text{ V}$	$I_{DQ} = 250\text{ mA}$ $P_{OUT} = 45\text{ W PEP}$	33	40		%
Load mismatch	$V_{DD} = 28\text{ V}$	$I_{DQ} = 250\text{ mA}$ $P_{OUT} = 45\text{ W}$ $f = 945\text{ MHz}$ ALL PHASE ANGLES	10:1			VSWR

note: $f_1 = 945\text{ MHz}$ PEP $f_2 = 945.1\text{ MHz}$

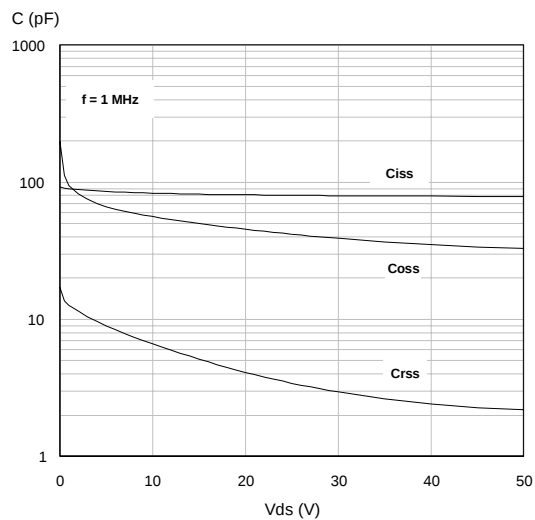
IMPEDANCE DATA



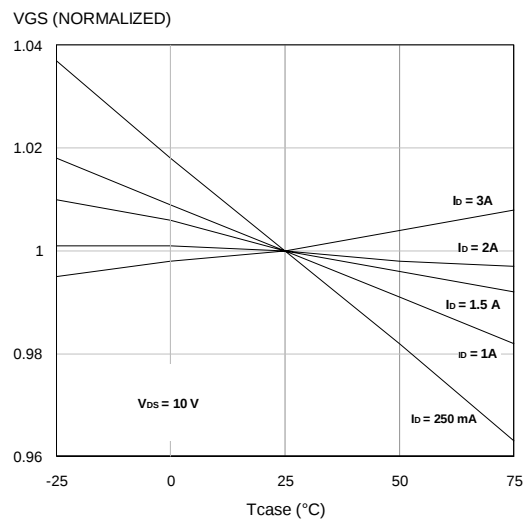
FREQ.	$Z_{IN} (\Omega)$	$Z_{DL}(\Omega)$
925 MHz	$1.27 + j\ 0.82$	$2.22 - j\ 1.63$
930 MHz	$1.21 + j\ 0.79$	$2.24 - j\ 1.61$
945 MHz	$1.04 + j\ 0.71$	$2.30 - j\ 1.52$
960 MHz	$0.93 + j\ 0.43$	$2.37 - j\ 1.37$
965 MHz	$0.91 + j\ 0.41$	$2.43 - j\ 1.36$

TYPICAL PERFORMANCE

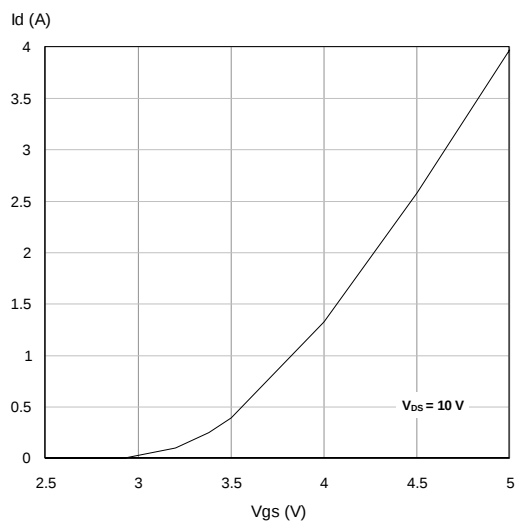
Capacitance vs. Drain Voltage



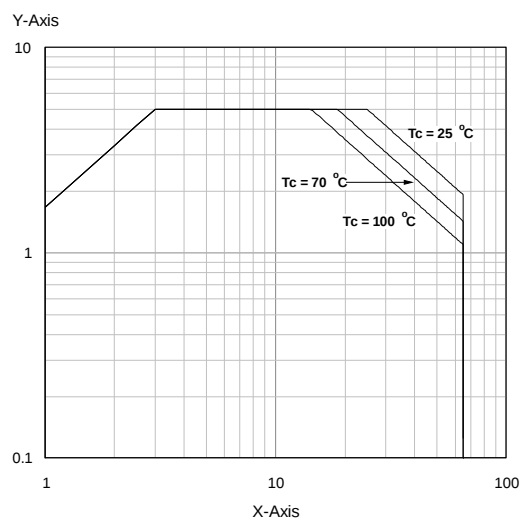
Gate-Source Voltage vs. Case Temperature



Drain Current vs. Gate Voltage



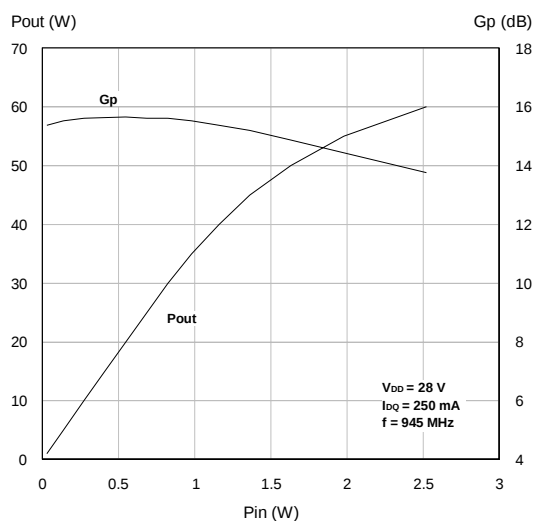
Safe Operating Area



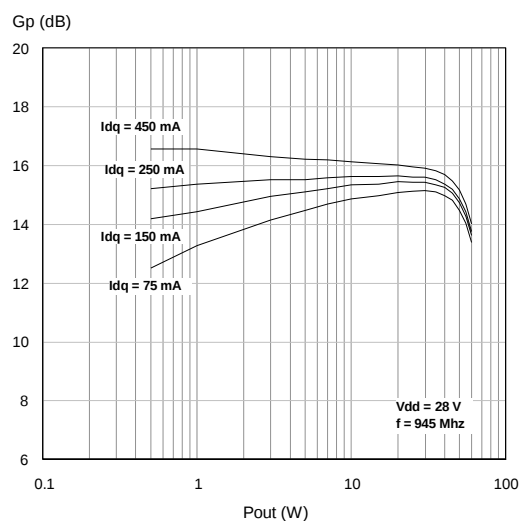
SD57045

TYPICAL PERFORMANCE (CW)

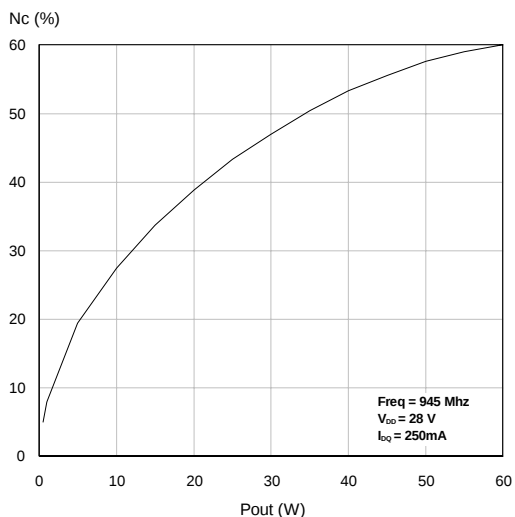
Output Power and Power Gain vs. Input Power



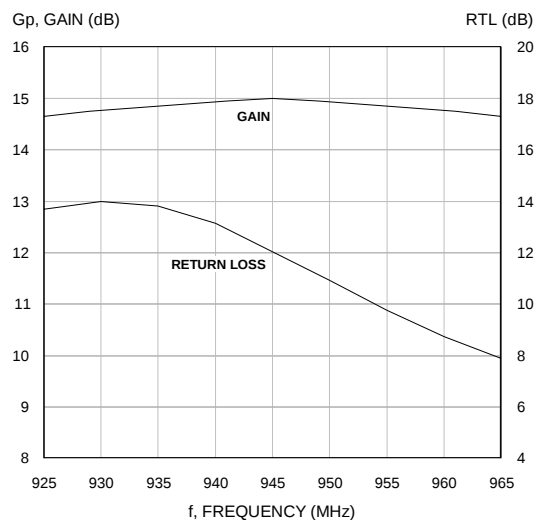
Power Gain vs. Output Power



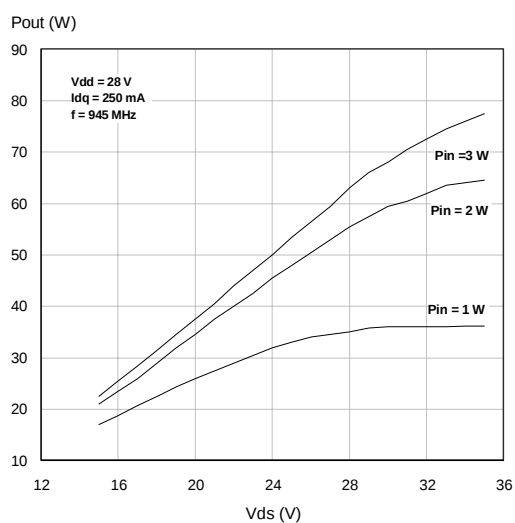
Efficiency vs. Output Power



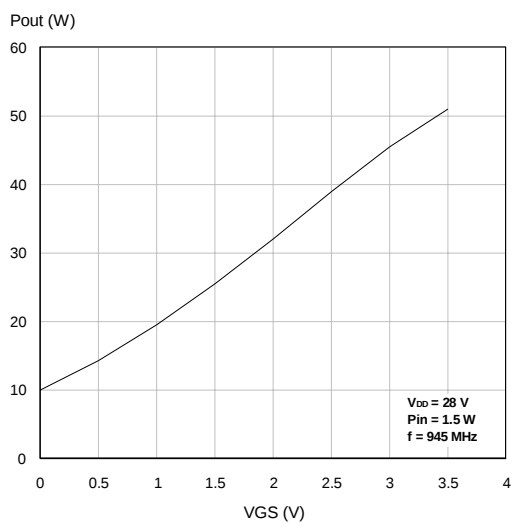
Broadband Power Performance



Output Power vs. Drain Voltage

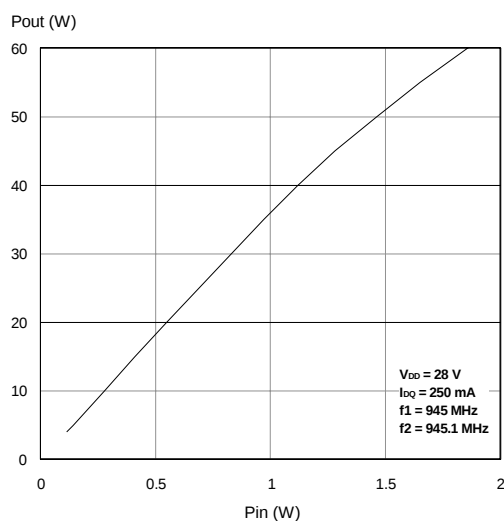


Output Power vs. Gate Bias Voltage

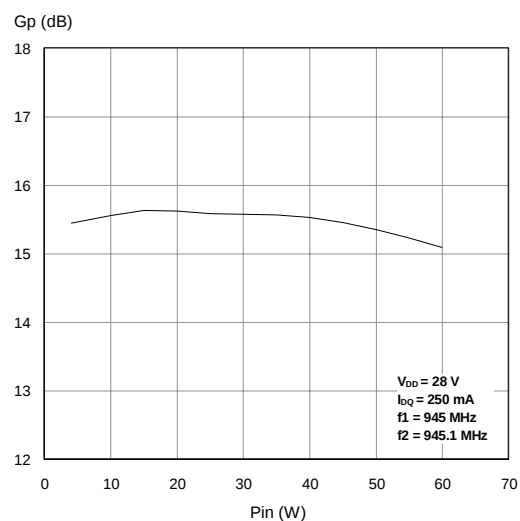


TYPICAL PERFORMANCE (PEP)

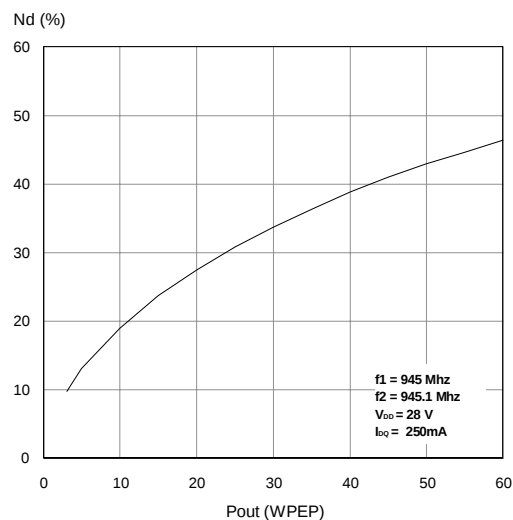
Output Power vs. Input Power



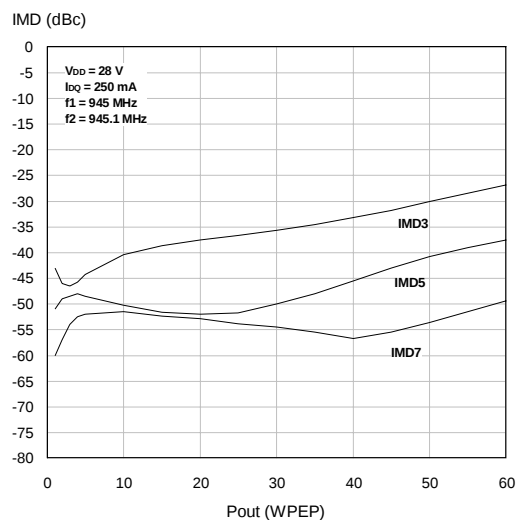
Power Gain vs. Input Power



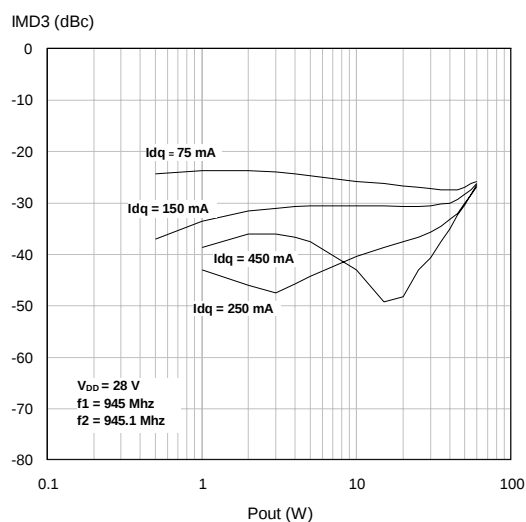
Efficiency vs. Output Power (PeP)



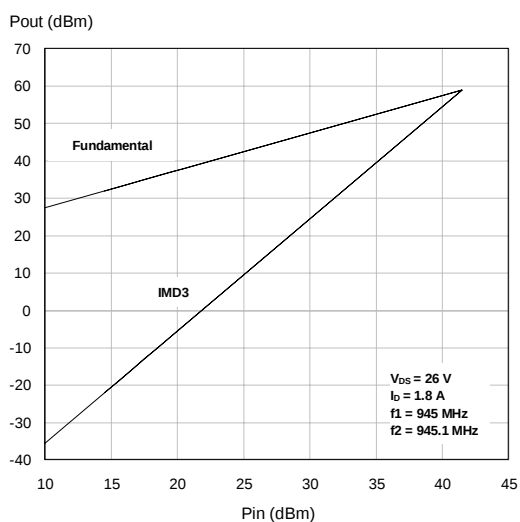
Intermodulation Distortion vs. Output Power



Intermodulation Distortion vs. Output Power



Class A Third Order Intercept Point



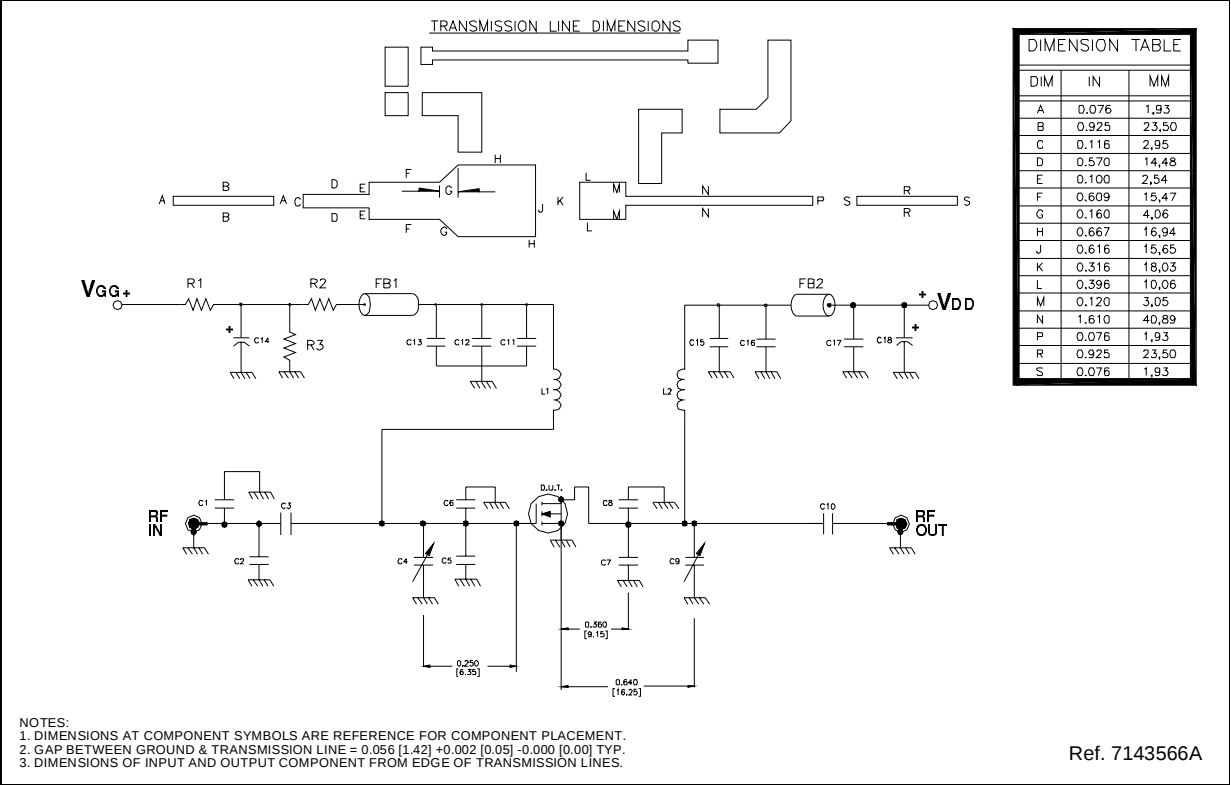
SD57045**COMMON SOURCE S-PARAMETER**(V_{DS} = 13.5 V I_{DS} = 2 A)

FREQ (MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠S ₂₂
50	0.902	-168	14.591	88	0.015	-4	0.781	-170
60	0.902	-169	13.845	88	0.015	-4	0.781	-170
70	0.902	-168	13.069	87	0.014	-5	0.781	-171
80	0.902	-170	12.266	86	0.014	-5	0.781	-171
90	0.902	-170	11.436	86	0.014	-5	0.782	-171
100	0.903	-171	10.587	84	0.014	-6	0.782	-172
150	0.905	-173	6.604	78	0.014	-9	0.788	-173
200	0.910	-174	4.670	71	0.013	-11	0.799	-173
250	0.916	-174	3.588	66	0.013	-12	0.812	-173
300	0.921	-174	2.884	61	0.012	-11	0.825	-173
350	0.927	-175	2.379	56	0.011	-13	0.839	-173
400	0.933	-175	2.005	52	0.011	-14	0.853	-173
450	0.939	-175	1.719	48	0.010	-14	0.866	-173
500	0.944	-175	1.494	45	0.010	-15	0.878	-173
550	0.950	-175	1.317	42	0.009	-14	0.889	-173
600	0.954	-175	1.169	40	0.008	-12	0.899	-173
650	0.957	-175	1.051	38	0.007	-10	0.908	-174
700	0.960	-175	0.942	36	0.007	-5	0.916	-174
750	0.963	-175	0.853	34	0.006	-1	0.923	-174
800	0.966	-175	0.770	32	0.005	7	0.930	-174
850	0.968	-176	0.696	31	0.005	16	0.935	-174
900	0.970	-176	0.630	29	0.005	28	0.940	-174
950	0.972	-176	0.568	28	0.005	40	0.944	-174
1000	0.973	-176	0.515	27	0.005	50	0.948	-174
1050	0.974	-176	0.465	26	0.006	59	0.950	-174
1100	0.926	-177	0.422	25	0.006	66	0.950	-174
1150	0.977	-177	0.301	25	0.007	74	0.949	-175
1200	0.979	-177	0.348	24	0.008	79	0.946	-176
1250	0.980	-177	0.317	24	0.009	83	0.941	-177
1300	0.982	-177	0.292	24	0.010	84	0.934	-178
1350	0.984	-177	0.267	24	0.011	85	0.923	180
1400	0.986	-177	0.248	24	0.012	86	0.910	177
1450	0.989	-177	0.231	24	0.013	87	0.892	175
1500	0.990	-177	0.223	25	0.013	88	0.898	172

COMMON SOURCE S-PARAMETER(V_{DS} = 28 V I_{DS} = 2 A)

FREQ (MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠S ₂₂
50	0.867	-158	20.011	91	0.013	2	0.675	-163
60	0.870	-159	18.979	90	0.013	1	0.676	-164
70	0.873	-160	17.907	89	0.013	-0	0.677	-164
80	0.876	-162	16.794	88	0.013	-1	0.679	-165
90	0.880	-163	15.649	87	0.013	-2	0.681	-165
100	0.884	-164	14.478	86	0.013	-3	0.683	-165
150	0.904	-169	8.997	77	0.012	-9	0.700	-167
200	0.915	-171	6.310	70	0.012	-14	0.722	-167
250	0.920	-172	4.797	62	0.011	-18	0.748	-167
300	0.927	-173	3.813	56	0.010	-21	0.774	-167
350	0.933	-173	3.106	51	0.009	-22	0.799	-167
400	0.940	-173	2.589	47	0.009	-23	0.823	-168
450	0.947	-174	2.194	43	0.008	-23	0.843	-168
500	0.953	-174	1.890	40	0.007	-23	0.862	-168
550	0.958	-174	1.652	37	0.006	-21	0.877	-169
600	0.963	-174	1.456	34	0.006	-17	0.891	-169
650	0.966	-174	1.299	32	0.005	-12	0.904	-169
700	0.968	-175	1.157	30	0.004	-4	0.914	-170
750	0.971	-175	1.039	28	0.004	6	0.923	-170
800	0.974	-175	0.932	26	0.004	18	0.932	-170
850	0.976	-175	0.838	25	0.004	31	0.940	-172
900	0.977	-176	0.755	23	0.004	42	0.946	-170
950	0.979	-176	0.678	22	0.004	54	0.951	-170
1000	0.980	-176	0.613	21	0.005	61	0.955	-171
1050	0.981	-176	0.550	20	0.006	69	0.957	-171
1100	0.982	-177	0.498	19	0.006	74	0.958	-171
1150	0.983	-177	0.449	19	0.007	28	0.957	-172
1200	0.985	-177	0.410	19	0.008	80	0.954	-173
1250	0.985	-177	0.373	18	0.009	83	0.949	-174
1300	0.986	-177	0.344	18	0.010	86	0.940	-175
1350	0.987	-177	0.314	18	0.010	88	0.929	-177
1400	0.989	-177	0.292	19	0.011	90	0.913	-180
1450	0.991	-177	0.273	19	0.012	93	0.896	-177
1500	0.992	-177	0.263	19	0.013	94	0.884	-175

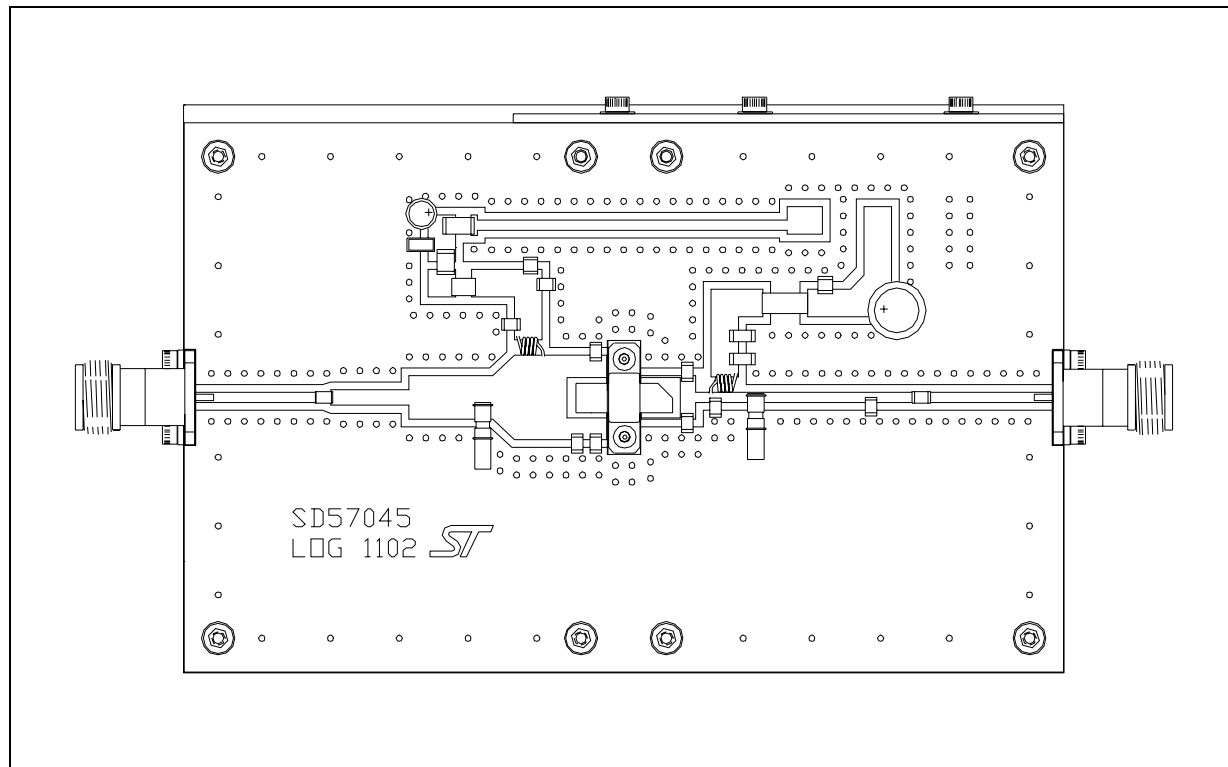
945 MHz TEST CIRCUIT SCHEMATIC



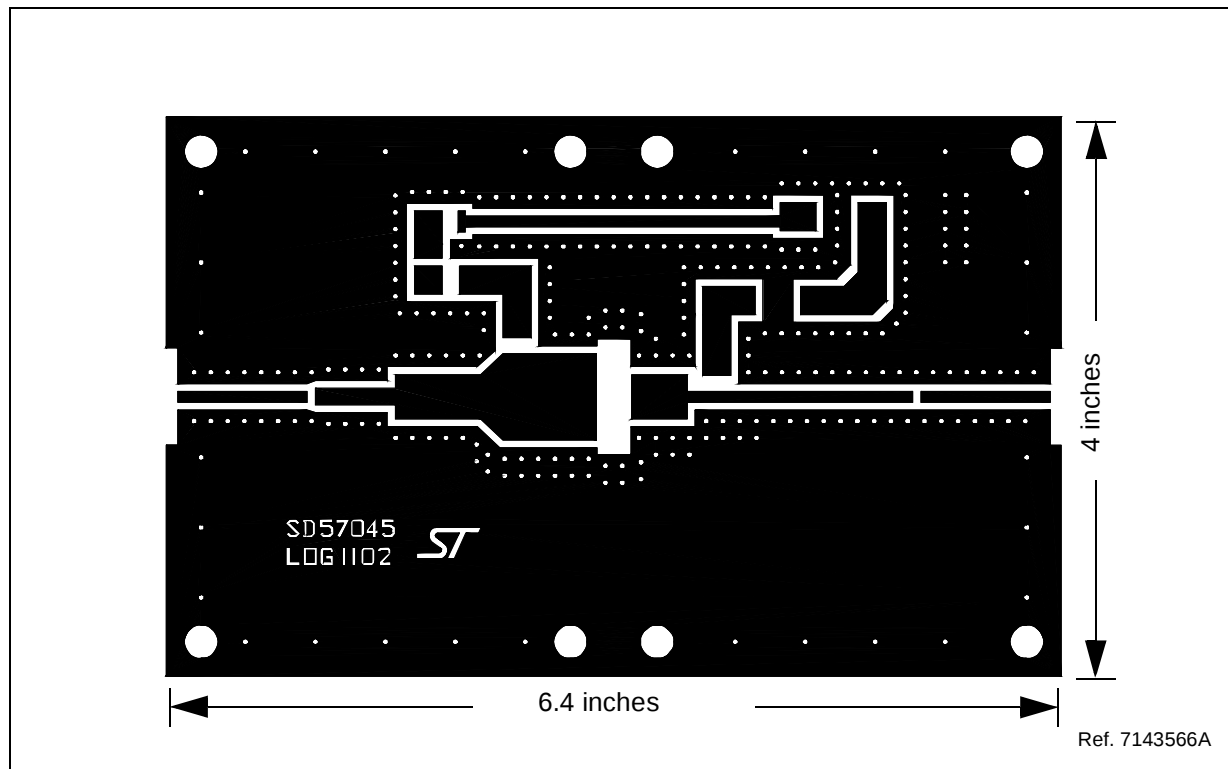
945 MHz TEST CIRCUIT COMPONENT PART LIST

COMPONENT	DESCRIPTION
C19	220 μF/ 63V ALUMINUM ELECTROLYTIC RADIAL LEAD CAPACITOR
C18, C14	0.1 μF/500 V SURFACE MOUNT CERAMIC CHIP CAPACITOR
C17	100 pF ATC 100B SURFACE MOUNT CERAMIC CHIP CAPACITOR
C16, C12, C11, C1	47 pF ATC 100B SURFACE MOUNT CERAMIC CHIP CAPACITOR
C15	10 μF/50 V ALUMINUM ELECTROLYTIC RADIAL LEAD CAPACITOR
C13	1000 pF ATC 700B SURFACE MOUNT CERAMIC CHIP CAPACITOR
C10	3.0 pF ATC 100B SURFACE MOUNT CERAMIC CHIP CAPACITOR
C9, C2	0.8 - 8.0 pF GIGA TRIM VARIABLE CAPACITOR
C8	6.2 pF ATC 100B SURFACE MOUNT CERAMIC CHIP CAPACITOR
C7, C6, C5, C4	10 pF ATC 100B SURFACE MOUNT CERAMIC CHIP CAPACITOR
C3	3 pF ATC 100B SURFACE MOUNT CERAMIC CHIP CAPACITOR
R3	120 OHM, 2W SURFACE MOUNT CHIP RESISTOR
R2	4.7M OHM, 1W SURFACE MOUNT CHIP RESISTOR
R1	18K OHM, 1W SURFACE MOUNT CHIP RESISTOR
FB2	SHIELD BEAD SURFACE MOUNT EMI
FB1	SHIELD BEAD SURFACE MOUNT EMI
L2	INDUCTOR, 5TURNS AIR WOUND #22AWG, ID=0.059[1.49], NYLON COATED MAGNET WIRE
L1	INDUCTOR, 5TURNS AIR WOUND #22AWG, ID=0.059[1.49], NYLON COATED MAGNET WIRE
PCB	WOVEN FIBERGLASS REINFORCED PTFE 0.080" THK, εr=2.55, 2 Oz EDCu BOTH SIDE

945 MHz PRODUCTION TEST FIXTURE

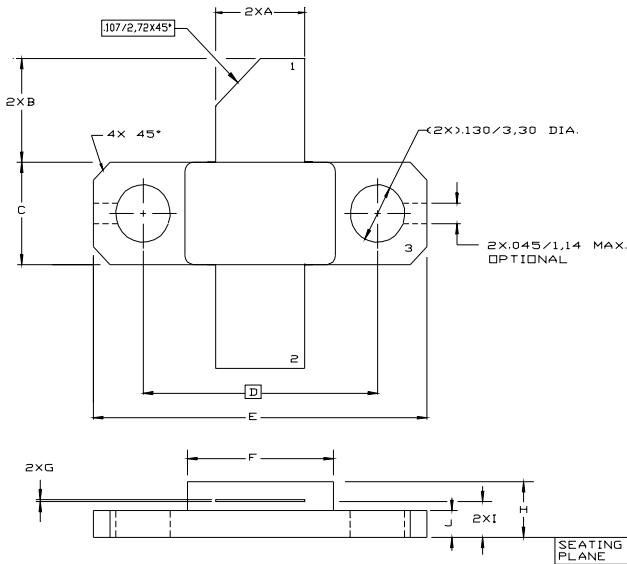


945 MHz TEST CIRCUIT PHOTOMASTER



M243 (.230 x .360 2L N/HERM W/FLG) MECHANICAL DATA

DIM.	mm			Inch		
	MIN.	TYP.	MAX	MIN.	TYP.	MAX
A	5.21		5.72	0.205		0.225
B	5.46		6.48	0.215		0.255
C	5.59		6.10	0.220		0.240
D		14.27			0.562	
E	20.07		20.57	0.790		0.810
F	8.89		9.40	0.350		0.370
G	0.10		0.15	0.004		0.006
H	3.18		4.45	0.125		0.175
I	1.83		2.24	0.072		0.088
J	1.27		1.78	0.050		0.070



Controlling dimension: Inches

1022142E

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➤ Sales :

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

➤ Customer Service :

Email service@ameya360.com

➤ Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com